

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRFS7540

• FEATURES

- With TO-263(D2PAK) packaging
- · High speed switching
- · Low gate input resistance
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

· Power supply

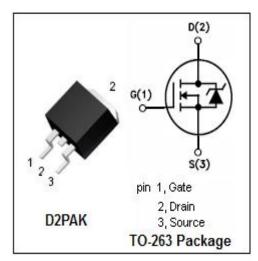
Switching applications

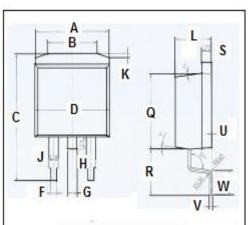
• ABSOL				
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	60	V	
V _{GSS}	Gate-Source Voltage	±20	∧v	
lD	Drain Current-Continuous;Tc=25℃ Tc=100℃	110 80	A	
I _{DM}	Drain Current-Single Pulsed	430	А	
P _D	Total Dissipation	160	W	
Tj	Operating Junction Temperature	175	°C	
T _{stg}	Storage Temperature	-55~175	°C	

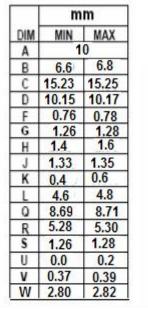
• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.95	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	

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isc website: www.iscsemi.cn

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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	60			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.1mA	2.3		3.8	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =65A		4.2	5.1	mΩ
lgss	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =60V; V _{GS} = 0V;Tc=25°C V _{DS} =60V; V _{GS} = 0V; Tc=125°C			1 150	μA
V _{SDF}	Diode forward voltage	I _{SD} =65A, V _{GS} = 0 V			1.2	V

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